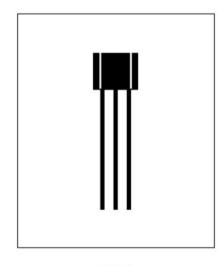


#### **Features**

- High sensitivity
- Digital output signal
- Zero speed detection
- Short circuit protection
- Insensitive to orientation
- Wide voltage working range
- Self-adjusting magnetic range
- On-chip 12 bit A/D converter
- High speed operation
- No chopper delay applications
- RoHS compliant



SIP-3

### **Application**

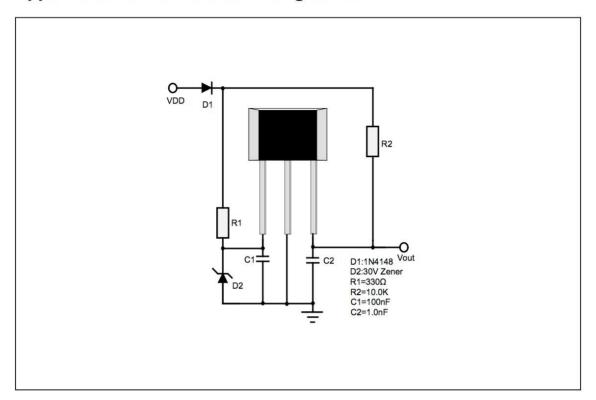
- Camshaft sensor
- Gear tooth sensor
- Speed sensor
- Direction detection

The HL900G is a sophisticated IC featuring an on-chip 12-bit A/D Converter and logic that acts as a digital sample and hold circuit . A separate 6-bit D/A converter provides a fixed hysteresis . The HL900G does not have a chopper delay . The HL900G uses a single Hall plate which is immune to rotary alignment problems . The bias magnet can be from 1000GS to 4000Gs . As the signal is sampled, the logic recognizes an increasing or decreasing flux density.

The output will turn on (BOP) after the flux has reached its peak and decreased by an amount equal to the hysteresis. Similarly the output will turn off (BRP) after the flux has reached its minimum value and increased by an amount equal to the hysteresis.



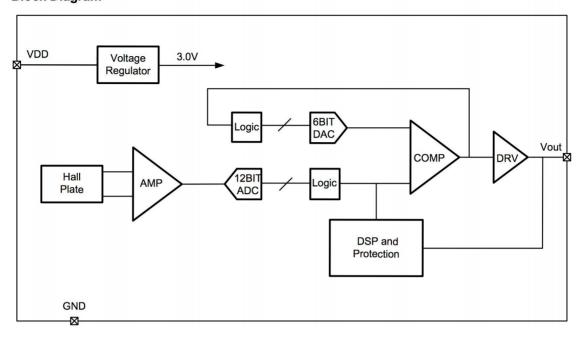
# **Application Circuit and Pin Configuration**



| Number | Name | Function                      |
|--------|------|-------------------------------|
| 1      | VDD  | Connects power supply to chip |
| 2      | GND  | Ground terminal               |
| 3      | Vout | Signal Output                 |



### **Block Diagram**



## **Absolute Maximum Rating**

| Parameter                                    | Limit Values |       |  |  |
|--|--------------|-------|--|--|
|  | Min.         | Max.  |  |  |
| Supply Voltage (Operating), VDD              | -0.3V        | 30V   |  |  |
| Output Voltage, Vo                           | -0.3V        | 30V   |  |  |
| Supply Current (Fault), IDD                  |              | 50mA  |  |  |
| Output Current (Fault), IOUT                 |              | 30mA  |  |  |
| Output Current (Fault), Ifault               |              | 200mA |  |  |
| Junction temperature, T <sub>J</sub> (5000h) |              | 150°C |  |  |
| Junction temperature, T <sub>J</sub> (2000h) |              | 160°C |  |  |
| Junction temperature, T <sub>J</sub> (1000h) |              | 170°C |  |  |
| Junction temperature, T <sub>J</sub> (100h)  |              | 180°C |  |  |
| Operating Temperature Range, TA              | - 40°C       | 150°C |  |  |
| Storage Temperature Range, Ts                | - 65°C       | 150°C |  |  |

## **ESD Protection**

Human Body Model (HBM) tests

| Parameter            | Symbol | Max. | Unit | Note                  |
|----------------------|--------|------|------|-----------------------|
| ESD V <sub>ESD</sub> |        | 8    | kV   | According to standard |
|                      |        |      |      | EIA/JESD22-A114-B HBM |



# **Electrical Specifications**

### DC Operating Parameters TA = -40°C to 150°C, VDD = 4.0V to 30V (unless otherwise specified)

| Parameter                     | Symbol Test Conditions |   | Min | Тур | Max | Unit   |
|-------------------------------|------------------------|---|-----|-----|-----|--------|
| Supply Voltage                | V <sub>DD</sub>        | Operating                                       | 4.0 | 12  | 30  | ٧      |
| Supply Current                | IDD                    | V <sub>DD</sub> = 12V                           | 1.5 | 3.0 | 4.5 | mA     |
| Power-Up State                | POS                    | VDD > VDD( min)                                 | Н   | Н   | Н   |        |
| Supply Current                | IDD                    | V <sub>DD</sub> = 4.0V to 30V                   | 1.0 |     | 6.0 | mA     |
| Leakage Current               | ILEAK                  | Vout = 4.0V to 30V                              |     |     | 10  | uA     |
| Output Current                | louт                   | Operating                                       |     |     | 25  | mA     |
| Output Saturation Voltage     | VSAT                   | V <sub>DD</sub> = 12V, I <sub>OUT</sub> = 25 mA |     |     | 600 | mV     |
| Output Current Limit          | Limit                  | V <sub>DD</sub> = 12V                           | 50  | 100 | 150 | mA     |
| Output Short Circuit Shutdown | TFAULT                 | Fault   | 10  |     | 20  | uS     |
| Clock Frequency               | Fclk                   | Operating                                       | 400 | 500 | 600 | KHz    |
| Output Rise Time              | Tr                     | V <sub>DD</sub> =12V, R1 = 1.0K,                |     |     | 400 | nS     |
|                               |                        | Cload=10pF                                      |     |     |     |        |
| Output Fall Time              | Tf                     | $V_{DD}=12V R1 = 1.0K,$                         |     |     | 400 | nS     |
|                               |                        | Cload=10pF                                      |     |     |     | 14     |
| Bandwidth                     | BW                     | Operating                                       |     |     | 15  | KHz    |
| Thermal Resistance            | RTH                    | Operating                                       |     |     | 200 | ℃/Watt |

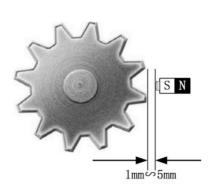
# **Magnetic Specifications**

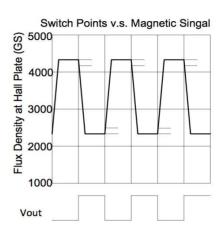
### DC Operating Parameters TA = -40 °C to 150 °C, VDD = 4.0V to 30V (unless otherwise specified)

| Parameter       | Symbol | Test Conditions       | Min | Тур | Max  | Units |
|-----------------|--------|-----------------------|-----|-----|------|-------|
| Back Bias Range | Выаѕ   | Operating             | -30 |     | 4000 | Gs    |
| Linear Region   |        | V <sub>DD</sub> = 12V | 500 |     | 5000 | Gs    |
| Hysteresis      | Bhys   |                       | 10  |     | 80   | Gs    |

10Gs=1mT

### **Gear Tooth Sensing**





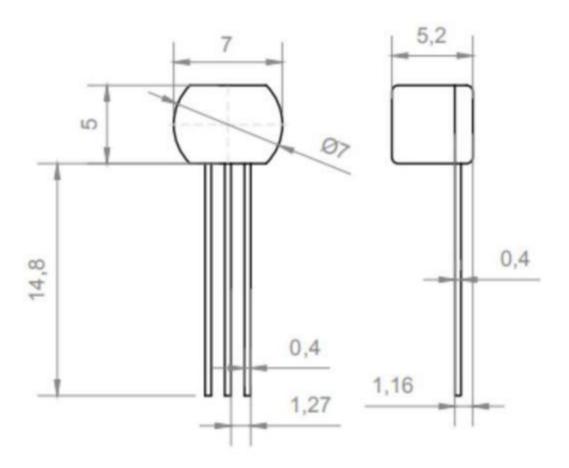
In the case of Ferromagnetic toothed wheel application the IC has to be biased by the south pole of a permanent magnet (Maximum  $4000\,\text{Gs}$ ). When assemble the sensor system, suggest choose a magnet as back bias flux from  $1000\,\text{Gs}$  to  $4000\,\text{Gs}$ . Normally the South pole of magnet faces the unbranded side of the IC and be glued to the back surface (non branded side) of the IC using a adhesive or suitable epoxy. Duo to the HL900G is "Self adjusting" over a wide range of back bias flux eliminating the need for any trimming in the application.

At the chip power on state, the output is reset to the high state whatever the field is . The output only changes after the first min is detected . The reset state holds no information about the field . If the supply of the chip is raised slowly, the reset state is not stable; the output maybe can't set to the high state . The maximum air gap depends on

- the magnetic field strength (magnet used; pre-induction) and
- the toothed wheel that is used (dimensions, material, ect.) It is strongly recommended that an external ceramic bypass capacitor in the range 10 nF to 1 uF be connected between the supply and ground of the device to reduce external noise. The series resistor in combination with the bypass capacitor creates a filter for EMC pulse. The pull- up resistor should be chosen to limit the current though the output transistor; do not exceed the maximum continuous output current of the device.



## **Package**



#### Notes:

- 1 . Exact body and lead configuration at vendor's option within limits shown .
- 2 . Height does not include mold gate flash .
- 3 .Where no tolerance is specified, dimension is nominal .